



FZT603

80V NPN DARLINGTON TRANSISTOR IN SOT223

Features

- BVcEo > 80V
- BVcBo > 100V
- Ic = 2A High Continuous Current
- Useful hfe up to 6A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (FZT603Q)

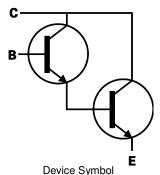
Mechanical Data

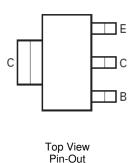
- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 (23)
- Weight: 0.112 grams (Approximate)





Top View





Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Part Nulliber				rape widin (ililii)	Qty.	Carrier
FZT603TA	SOT223 (Type DN)	FZT603	7	12	1,000	Reel

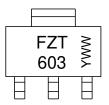
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

SOT223 (Type DN)



FZT603 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W = Week Code (01 to 53)$

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	VCEO	80	V
Emitter-Base Voltage	V _{EBO}	10	V
Continuous Collector Current	Ic	2	Α
Peak Pulse Current	Ісм	6	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Power Dissipation	(Note 6)	D	2.0	W	
Power Dissipation	(Note 7)	P _D	1.6		
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	Б	62.5		
Thermal Resistance, Junction to Ambient	(Note 7)	RθJA	78.1	°C/W	
	(Note 8)		104	1	
Thermal Resistance Junction to Lead (Note 9)		ReJL	12.9		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	200	V	В

Notes:

- 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

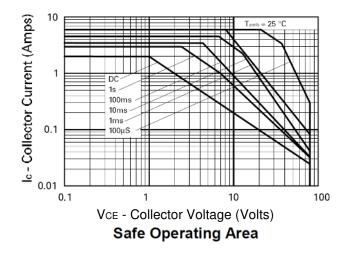
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

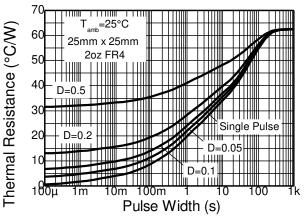
 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

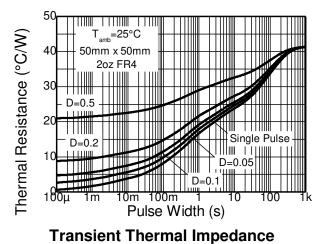
 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



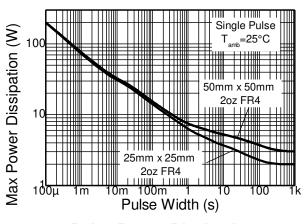
Thermal Characteristics and Derating Information

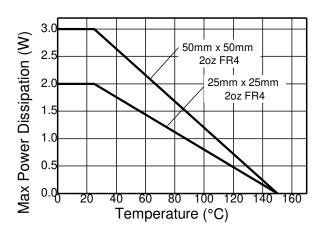






Transient Thermal Impedance





Pulse Power Dissipation

Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

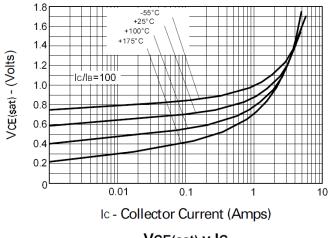
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	ВУсво	100	240	_	V	$I_C = 100\mu A$	
Collector-Emitter Breakdown Voltage (Note 11)	BVceo	80	110	_	V	Ic = 10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	10	16	_	V	I _E = 100μA	
Collector-Base Cut-Off Current	Ісво	_	_	10 10	nA μA	V _{CB} = 80V V _{CB} = 80V, T _A = +100°C	
Collector-Emitter Cut-Off Current	ICES	_	_	10	μΑ	Vces = 80V	
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 8V	
DC Current Gain (Note 11)	h _{FE}	3,000 5,000 3,000 2,000 —	14,000 15,000 14,000 10,000 2,000 750	100,000 — — — — —	111111	IC = 50mA, VCE = 5V IC = 500mA, VCE = 5V IC = 1A, VCE = 5V IC = 2A, VCE = 5V IC = 5A, VCE = 5V IC = 6A, VCE = 5V	
Collector-Emitter Saturation Voltage (Note 11)	VCE(sat)		0.79 0.80 0.88 0.99 0.86	0.88 0.90 1.00 1.13	٧	IC = 250mA, I _B = 0.25mA I _C = 0.4A, I _B = 0.4mA I _C = 1A, I _B = 1mA I _C = 2A, I _B = 20mA I _C = 2A, I _B = 20mA, T _J = +150°C	
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_	1.70	1.95	V	Ic = 2A, I _B = 20mA	
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	_	1.50	1.75	V	IC = 2A, VCE = 5V	
Input Capacitance (Note 11)	Cibo	_	90	_	pF	V _{EB} = 0.5V, f = 1MHz	
Output Capacitance (Note 11)	Cobo	_	15	_	pF	V _{CB} = 10V, f = 1MHz	
Current Gain-Bandwidth Product (Note 11)	f⊤	150	_	_	MHz	V _{CE} = 10V, I _C = 100mA f = 20MHz	
Turn-On Time	ton	_	0.5	_	μs	Vcc = 10V, Ic = 500mA	
Turn-Off Time	toff	_	1.6	_	μs	$I_{B1} = -I_{B2} = 0.5 \text{mA}$	

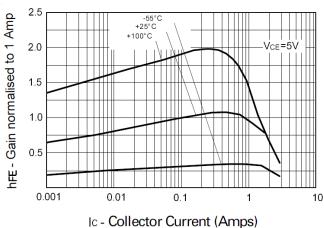
Note:

11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

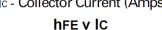


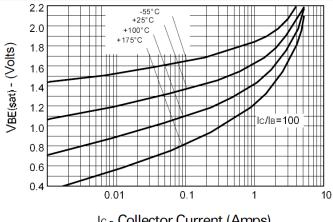
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

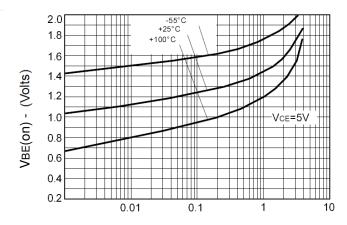




VCE(sat) v IC







Ic - Collector Current (Amps)

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VBE(sat) v IC

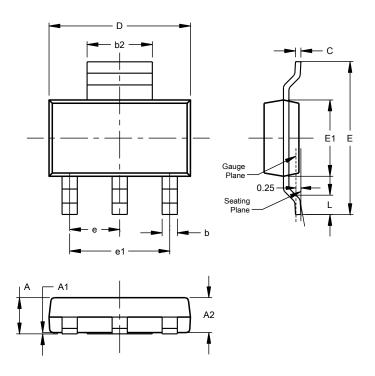
VBE(on) v IC



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

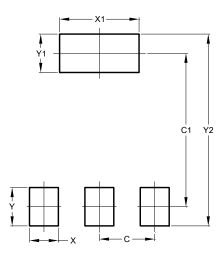


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1	-		4.60		
٦	0.85				
All Dimensions in mm					

Suggested Pad Layout

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for the \ latest \ version.$

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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